

## **80 A SCHOTTKY RECTIFIERS**

High-reliability discrete products and engineering services since 1977

#### FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

Rating	Symbol	MBR8035	MBR8045	Unit
Peak repetitive reverse voltage	V <sub>RRM</sub>			
Working peak reverse voltage	V <sub>RWM</sub>	35	45	v
DC blocking voltage	V <sub>R</sub>			
Peak repetitive forward current (Rated V <sub>R</sub> , square wave, 20kHz)	I <sub>FRM</sub>	160@ T <sub>c</sub> = 120°C		V
Average rectified forward current (Rated $V_R$ )	I <sub>o</sub>	80 @ T <sub>c</sub> = 120°C		А
Peak repetitive reverse surge current (2.0µs, 1.0kHz)	I <sub>RRM</sub>	2.0		А
Non-repetitive peak surge current ( $T_A = 70$ °C) (surge applied at rated load conditions, halfwave, single phase, 60Hz)	I <sub>FSM</sub>	1000		А
Operating junction and storage temperature range	T <sub>J,</sub> T <sub>stg</sub>	-65 to +175		°C
Voltage rate of change (Rated V <sub>R</sub> )	dv/dt	1000		V/µs
Maximum thermal resistance				°C/W
Junction to case	R <sub>eJC</sub>	0.80		

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	MBR8035	MBR8045	Unit
Instantaneous forward voltage (1)				
(I <sub>F</sub> = 80A, T <sub>C</sub> = 25°C)	VF	0.72	0.72	v
(I <sub>F</sub> = 80A, T <sub>C</sub> = 150°C)		0.59	0.59	
(I <sub>F</sub> = 160A, T <sub>C</sub> = 150°C)		0.67	0.67	
Instantaneous reverse current <sup>(1)</sup>				
(Rated dc voltage, $T_c = 25^{\circ}C$ )	I <sub>R</sub>	1.0		mA
(Rated dc voltage, $T_c = 150^{\circ}C$ )		150		
Capacitance ( $V_{BR}$ = 1.0VVdc, 100kHz $\leq$ f $\leq$ 1.0 MHz)	Ct	5000		pF

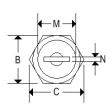


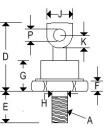
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#### MECHANICAL CHARACTERISTICS

Case	DO-5(R)	
Marking	Alpha-numeric	
Normal polarity	Cathode is stud	
Reverse polarity Anode is stud (add "R" suffix)		



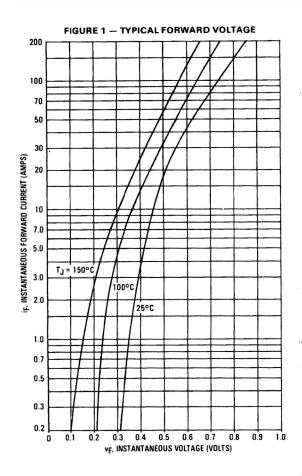


	DO-5(R)					
	Inches		Millimeters			
	Min	Max	Min	Max		
Α	¼-28 UNF2A threads					
В	0.669	0.688	16.990	17.480		
С	-	0.794	-	20.160		
D	-	1.000	-	25.400		
Ε	0.422	0.453	10.720	11.510		
F	0115	0.200	2.920	5.080		
G	-	0.450	-	11.430		
Н	0.220	0.249	5.580	6.320		
J	0.250	0.375	6.350	9.530		
К	0.156	-	3.960	-		
М	-	0.667	-	16.940		
Ν	0.030	0.080	0.760	2.030		
Р	0.140	0.175	3.560	4.450		



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#### NOTE 1 HIGH FREQUENCY OPERATION

Since current flow in a Schottky rectifier is the result of majority carrier conduction, it is not subject to junction diode forward and reverse recovery transients due to minority carrier injection and stored charge. Satisfactory circuit analysis work may be performed by using a model consisting of an ideal diode in parallel with a variable capacitance. (See Figure 4.)

Rectification efficiency measurements show that operation will be satisfactory up to several megahertz. For example, relative waveform rectification efficiency is approximately 70 per cent at 2.0 MHz, e.g., the ratio of dc power to RMS power in the load is 0.28 at this frequency, whereas perfect rectification would yield 0.406 for sine wave inputs. However, in contrast to ordinary junction diodes, the loss in waveform efficiency is not indicative of power loss; it is simply a result of reverse current flow through the diode capacitance, which lowers the dc output voltage.

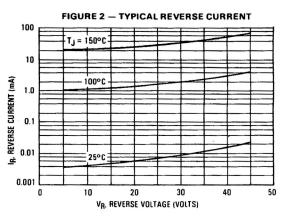
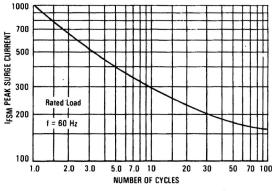
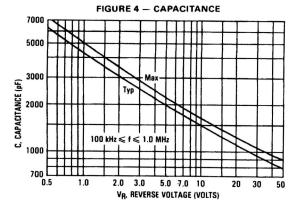


FIGURE 3 --- MAXIMUM SURGE CAPABILITY



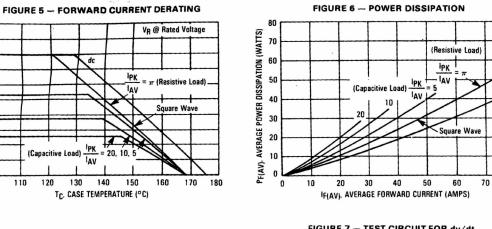




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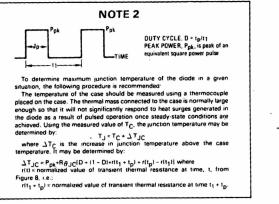
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IF(AV), AVERAGE FORWARD CURRENT (AMPS)





dc



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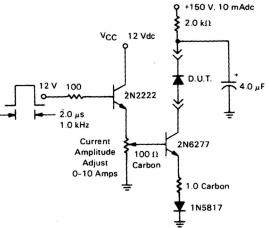


FIGURE 8 - THERMAL RESPONSE

